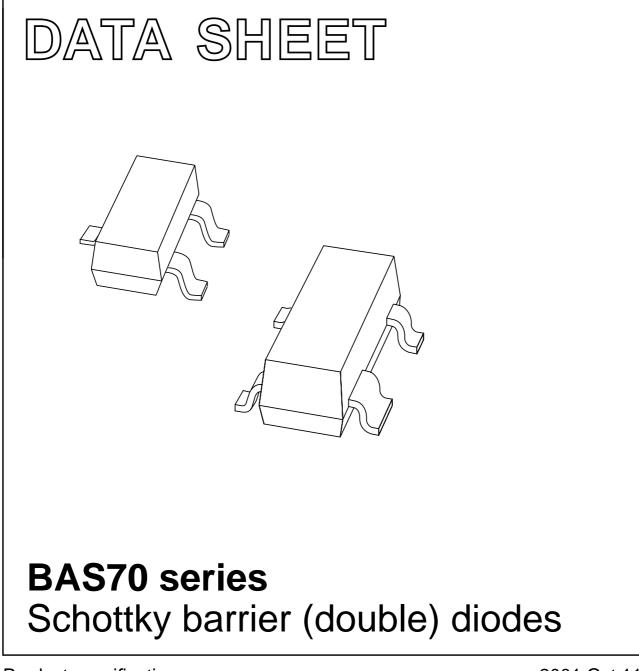
# DISCRETE SEMICONDUCTORS



Product specification Supersedes data of 1999 Jun 01 2001 Oct 11



PINNING

### **BAS70** series

### FEATURES

- Low forward current
- High breakdown voltage
- · Guard ring protected
- Small plastic SMD package
- Low diode capacitance.

### **APPLICATIONS**

- Ultra high-speed switching
- Voltage clamping
- Protection circuits.

### DESCRIPTION

Planar Schottky barrier diodes with an integrated guard ring for stress protection. Single diodes and double diodes with different pinning are available.

The diodes BAS70, BAS70-04, BAS70-05 and BAS70-06 are encapsulated in a SOT23 small plastic SMD package. The BAS70-07 is encapsulated in a SOT143B small plastic SMD package.

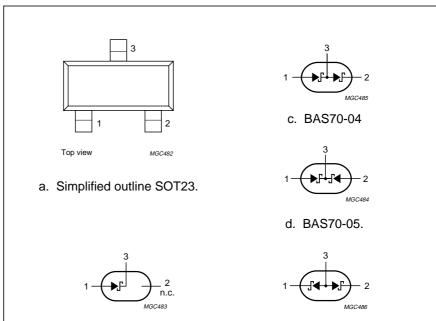
### MARKING

TYPE NUMBER	MARKING CODE <sup>(1)</sup>
BAS70	73*
BAS70-04	74*
BAS70-05	75*
BAS70-06	76*
BAS70-07	77*

### Note

- 1. \* = p: Made in Hong Kong.
  - \* = t: Made in Malaysia.
  - \* = W: Made in China.

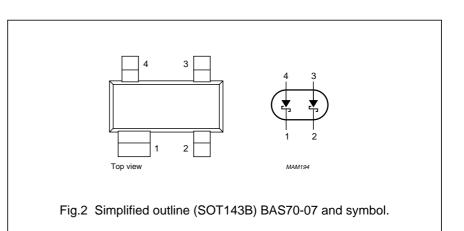
	DESCRIPTION				
PIN	SOT23				SOT143B
	BAS70 (see Fig.1b)	BAS70-04 (see Fig.1c)	BAS70-05 (see Fig.1d)	BAS70-06 (see Fig.1e)	BAS70-07 (see Fig.2)
1	a <sub>1</sub>	a <sub>1</sub>	a <sub>1</sub>	k <sub>1</sub>	k <sub>1</sub>
2	n.c.	k <sub>2</sub>	a <sub>2</sub>	k <sub>2</sub>	k <sub>2</sub>
3	k <sub>1</sub>	k <sub>1</sub> , a <sub>2</sub>	k <sub>1</sub> , k <sub>2</sub>	a <sub>1</sub> , a <sub>2</sub>	a <sub>2</sub>
4	_	_	_	_	a <sub>1</sub>



b. BAS70 single diode.

Fig.1 Simplified outline (SOT23) and symbols.

e. BAS70-06.



### **BAS70** series

### LIMITING VALUES

In accordance with the Absolute Maximum Rating System (IEC 60134).

SYMBOL	PARAMETER	CONDITIONS	MIN.	MAX.	UNIT	
Per diode	Per diode					
V <sub>R</sub>	continuous reverse voltage		-	70	V	
I <sub>F</sub>	continuous forward current		-	70	mA	
I <sub>FRM</sub>	repetitive peak forward current	$t_p \le 1 \text{ s}; \delta \le 0.5$	_	70	mA	
I <sub>FSM</sub>	non-repetitive peak forward current	t <sub>p</sub> < 10 ms	-	100	mA	
T <sub>stg</sub>	storage temperature		-65	+150	°C	
Tj	junction temperature		-	150	°C	
T <sub>amb</sub>	operating ambient temperature		-65	+150	°C	

### **ELECTRICAL CHARACTERISTICS**

 $T_{amb}$  = 25 °C unless otherwise specified.

SYMBOL	PARAMETER	CONDITIONS	MAX.	UNIT	
Per diode	Per diode				
V <sub>F</sub>	forward voltage	see Fig.3			
		I <sub>F</sub> = 1 mA	410	mV	
		I <sub>F</sub> = 10 mA	750	mV	
		I <sub>F</sub> = 15 mA	1	V	
I <sub>R</sub>	reverse current	$V_R = 50$ V; note 1; see Fig.4	100	nA	
		V <sub>R</sub> = 70 V; note 1; see Fig.4	10	μA	
τ	charge carrier life time (Krakauer method)	$I_F = 5 \text{ mA}$	100	ps	
C <sub>d</sub>	diode capacitance	$f = 1 \text{ MHz}; V_R = 0; \text{ see Fig.6}$	2	pF	

#### Note

1. Pulse test:  $t_p = 300 \ \mu s$ ;  $\delta = 0.02$ .

#### THERMAL CHARACTERISTICS

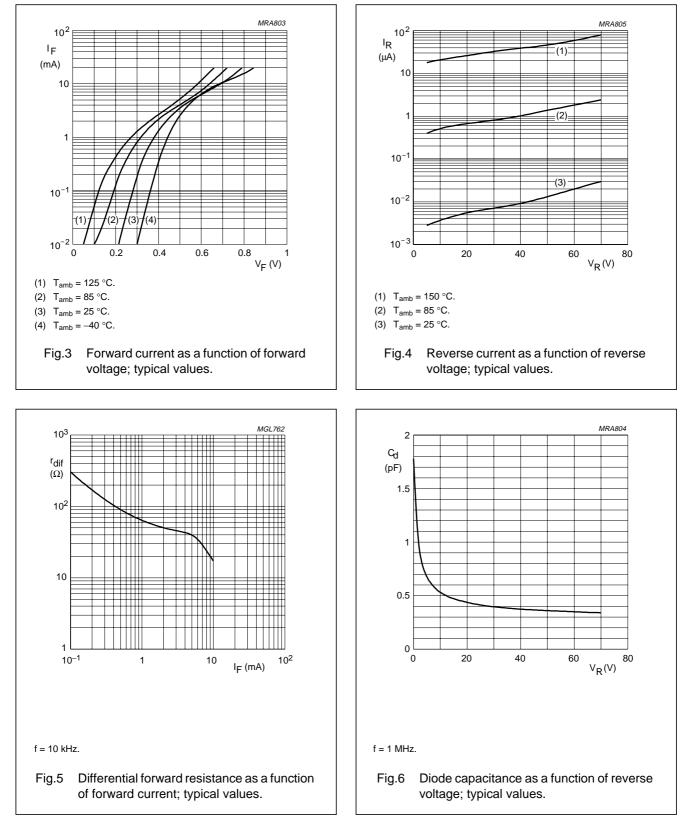
SYMBOL	PARAMETER	CONDITIONS	VALUE	UNIT
R <sub>th j-a</sub>	thermal resistance from junction to ambient	note 1	500	K/W

#### Note

1. Refer to SOT23 or SOT143B standard mounting conditions.

### **BAS70** series

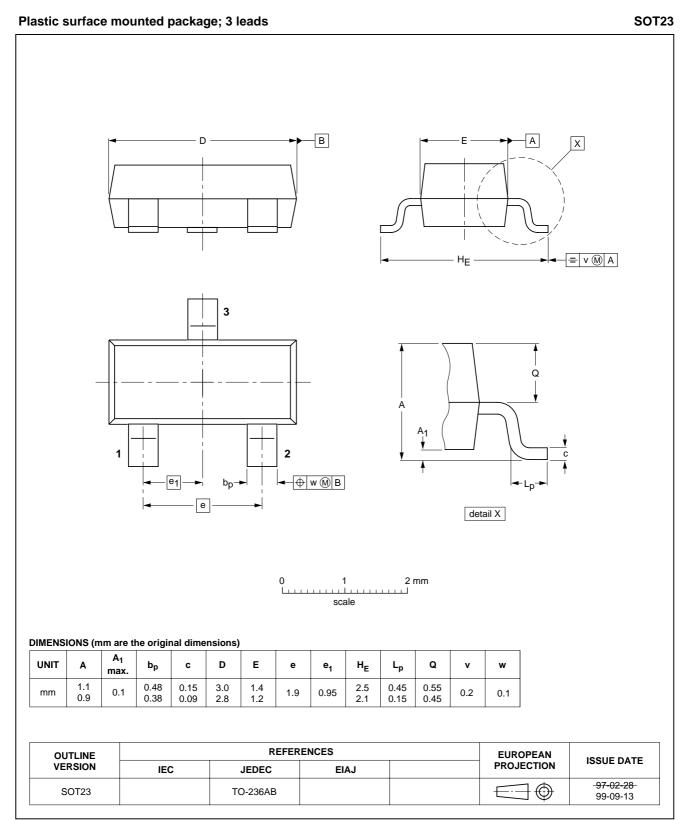
#### **GRAPHICAL DATA**



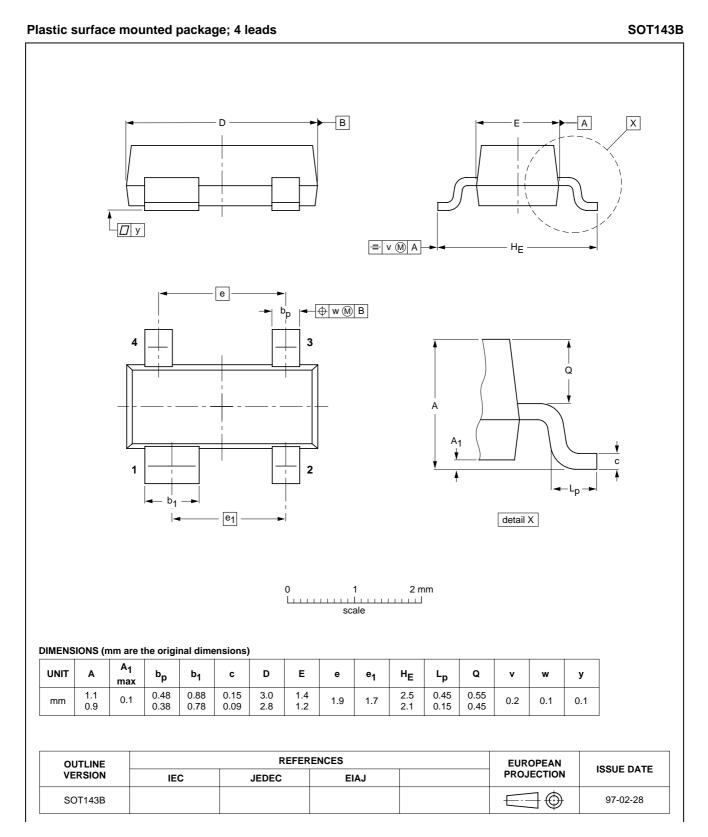
**BAS70** series

## Schottky barrier (double) diodes

### PACKAGE OUTLINES



### BAS70 series



**BAS70** series

#### DATA SHEET STATUS

DATA SHEET STATUS <sup>(1)</sup>	PRODUCT STATUS <sup>(2)</sup>	DEFINITIONS
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